

2N5301 2N5302 2N5303

HIGH-POWER NPN SILICON TRANSISTORS

... for use in power amplifier and switching circuits applications.

- High Collector-Emitter Sustaining Voltage –
 $V_{CEO(sus)} = 80 \text{ Vdc (Min) @ } I_C = 200 \text{ mAdc (2N5303)}$
- Low Collector-Emitter Saturation Voltage –
 $V_{CE(sat)} = 0.75 \text{ Vdc (Max) @ } I_C = 10 \text{ Adc (2N5301, 2N5302)}$
 $1.0 \text{ Vdc (Max) @ } I_C = 10 \text{ Adc (2N5303)}$
- Excellent Safe Operating Area –
200 Watt dc Power Rating to 30 Vdc (2N5303)
- Complements to PNP 2N4398, 2N4399 and 2N5745

*MAXIMUM RATINGS

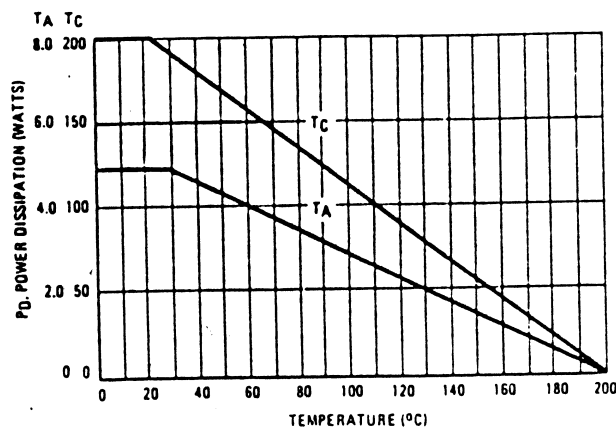
Rating	Symbol	2N5301	2N5302	2N5303	Unit
Collector-Emitter Voltage	V_{CEO}	40	60	80	Vdc
Collector-Base Voltage	V_{CB}	40	60	80	Vdc
Collector Current – Continuous	I_C	30	30	20	Adc
Base Current	I_B	7.5			Adc
Total Device Dissipation @ $T_C = 25^\circ\text{C}$ Derate above 25°C	P_D	200			Watts
		1.14			W/ $^\circ\text{C}$
Operating and Storage Junction Temperature Range	T_J, T_{stg}	-65 to +200			$^\circ\text{C}$

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	θ_{JC}	0.875	$^\circ\text{C/W}$
Thermal Resistance, Case to Ambient	θ_{CA}	34	$^\circ\text{C/W}$

* Indicates JEDEC Registered Data.

FIGURE 1 – POWER TEMPERATURE DERATING CURVE

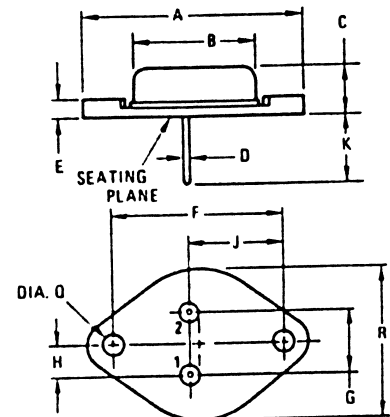
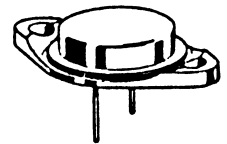


Quality Semi-Conductors

20 AND 30 AMPERE POWER TRANSISTORS

NPN SILICON

40-60-80 VOLTS
200 WATTS



STYLE 1:
PIN 1. BASE
2. EMITTER
CASE: COLLECTOR

NOTE:
1. DIM "O" IS DIA

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	-	39.37	-	1.550
B	-	21.08	-	0.830
C	6.35	7.62	0.250	0.300
D	0.99	1.09	0.039	0.043
E	-	3.43	-	0.135
F	29.90	30.40	1.177	1.197
G	10.67	11.18	0.420	0.440
H	5.33	5.59	0.210	0.220
J	16.64	17.15	0.655	0.675
K	11.18	12.19	0.440	0.480
Q	3.84	4.09	0.151	0.161
R	-	26.67	-	1.050

Collector connected to case.
CASE 11-01

ELECTRICAL CHARACTERISTICS ($T_C = 25^\circ$ unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
*OFF CHARACTERISTICS				
Collector-Emitter Sustaining Voltage (Note 1) ($I_C = 200 \text{ mA}$, $I_B = 0$)	$V_{CE(sus)}$	40 60 80	— — —	Vdc
Collector Cutoff Current ($V_{CE} = 40 \text{ Vdc}$, $I_B = 0$) ($V_{CE} = 60 \text{ Vdc}$, $I_B = 0$) ($V_{CE} = 80 \text{ Vdc}$, $I_B = 0$)	I_{CEO}	— — —	5.0 5.0 5.0	mA
Collector Cutoff Current ($V_{CE} = 40 \text{ Vdc}$, $V_{EB(off)} = 1.5 \text{ Vdc}$) ($V_{CE} = 60 \text{ Vdc}$, $V_{EB(off)} = 1.5 \text{ Vdc}$) ($V_{CE} = 80 \text{ Vdc}$, $V_{EB(off)} = 1.5 \text{ Vdc}$)	I_{CEX}	— — —	1.0 1.0 1.0	mA
Collector Cutoff Current ($V_{CE} = 40 \text{ Vdc}$, $V_{EB(off)} = 1.5 \text{ Vdc}$, $T_C = 150^\circ\text{C}$) ($V_{CE} = 60 \text{ Vdc}$, $V_{EB(off)} = 1.5 \text{ Vdc}$, $T_C = 150^\circ\text{C}$) ($V_{CE} = 80 \text{ Vdc}$, $V_{EB(off)} = 1.5 \text{ Vdc}$, $T_C = 150^\circ\text{C}$)	I_{CEX}	— — —	10 10 10	mA
Collector Cutoff Current ($V_{CB} = 40 \text{ Vdc}$, $I_E = 0$) ($V_{CB} = 60 \text{ Vdc}$, $I_E = 0$) ($V_{CB} = 80 \text{ Vdc}$, $I_E = 0$)	I_{CBO}	— — —	1.0 1.0 1.0	mA
Emitter Cutoff Current ($V_{BE} = 5.0 \text{ Vdc}$, $I_C = 0$)	I_{EBO}	—	5.0	mA

ON CHARACTERISTICS

DC Current Gain (Note 1) *($I_C = 1.0 \text{ A}$, $V_{CE} = 2.0 \text{ Vdc}$) *($I_C = 10 \text{ A}$, $V_{CE} = 2.0 \text{ Vdc}$) *($I_C = 15 \text{ A}$, $V_{CE} = 2.0 \text{ Vdc}$) *($I_C = 20 \text{ A}$, $V_{CE} = 4.0 \text{ Vdc}$) *($I_C = 30 \text{ A}$, $V_{CE} = 4.0 \text{ Vdc}$)	ALL TYPES 2N5303 2N5301, 2N5302 2N5303 2N5301, 2N5302	h_{FE}	40 15 15 5.0 5.0	— 60 60 — —	—
*Collector-Emitter Saturation Voltage (Note 1) ($I_C = 10 \text{ A}$, $I_B = 1.0 \text{ A}$) ($I_C = 10 \text{ A}$, $I_B = 1.0 \text{ A}$) ($I_C = 15 \text{ A}$, $I_B = 1.5 \text{ A}$) ($I_C = 20 \text{ A}$, $I_B = 2.0 \text{ A}$) ($I_C = 20 \text{ A}$, $I_B = 4.0 \text{ A}$) ($I_C = 30 \text{ A}$, $I_B = 6.0 \text{ A}$)	2N5301, 2N5302 2N5303 2N5303 2N5301, 2N5302 2N5303 2N5301, 2N5302	$V_{CE(sat)}$	— — — — — —	0.75 1.0 1.5 2.0 2.0 3.0	Vdc
*Base-Emitter Saturation Voltage (Note 1) ($I_C = 10 \text{ A}$, $I_B = 1.0 \text{ A}$) ($I_C = 15 \text{ A}$, $I_B = 1.5 \text{ A}$) ($I_C = 15 \text{ A}$, $I_B = 1.5 \text{ A}$) ($I_C = 20 \text{ A}$, $I_B = 2.0 \text{ A}$) ($I_C = 20 \text{ A}$, $I_B = 4.0 \text{ A}$)	ALL TYPES 2N5301, 2N5302 2N5303 2N5301, 2N5302 2N5303	$V_{BE(sat)}$	— — — — —	1.7 1.8 2.0 2.5 2.5	Vdc
*Base-Emitter On Voltage (Note 1) ($I_C = 10 \text{ A}$, $V_{CE} = 2.0 \text{ Vdc}$) ($I_C = 15 \text{ A}$, $V_{CE} = 2.0 \text{ Vdc}$) ($I_C = 20 \text{ A}$, $V_{CE} = 4.0 \text{ Vdc}$) ($I_C = 30 \text{ A}$, $V_{CE} = 4.0 \text{ Vdc}$)	2N5303 2N5301, 2N5302 2N5303 2N5301, 2N5302	$V_{BE(on)}$	— — — —	1.5 1.7 2.5 3.0	Vdc

***DYNAMIC CHARACTERISTICS**

Current Gain - Bandwidth Product ($I_C = 1.0 \text{ A}$, $V_{CE} = 10 \text{ Vdc}$, $f = 1.0 \text{ MHz}$)	f_T	20	—	MHz
Small-Signal Current Gain ($I_C = 1.0 \text{ A}$, $V_{CE} = 10 \text{ Vdc}$, $f = 1.0 \text{ kHz}$)	h_{fe}	40	—	—

***SWITCHING CHARACTERISTICS**

Rise Time	$(V_{CC} = 30 \text{ Vdc}, I_C = 10 \text{ A}, I_{B1} = I_{B2} = 1.0 \text{ A})$	t_r	—	1.0	μs
Storage Time		t_s	—	2.0	μs
Fall Time		t_f	—	1.0	μs

*Indicates JEDEC Registered Data

Note 1: Pulse Test: Pulse Width $\leq 300 \mu\text{s}$, Duty Cycle $\leq 2.0\%$

SWITCHING TIME EQUIVALENT TEST CIRCUITS

FIGURE 2 — TURN-ON TIME

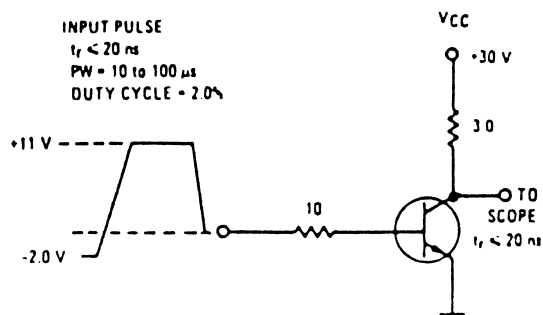


FIGURE 3 — TURN-OFF TIME

